

虹冠電子

Champion Microelectronic Corp.

<http://www.championmicro.com.tw>

Dr. FlybackTM

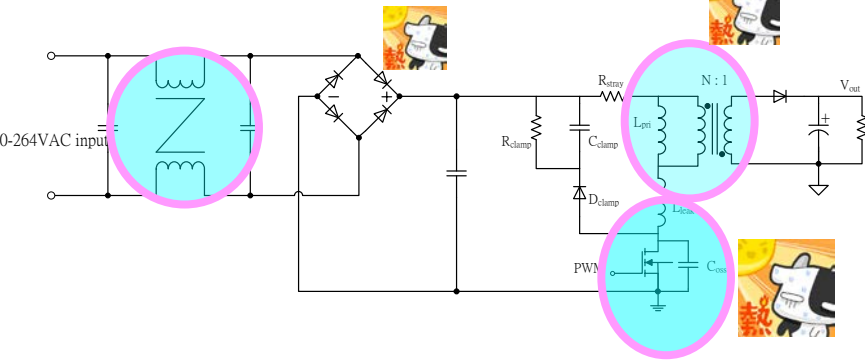
The Best Flyback = Dr. FlybackTM

CUDrFB (Dr. Flyback™) from Champion

- ✓ **Build-in High Side 800V Power Mosfet (800V High Side Driver Inside)**
- ✓ **Always ZVS for both Power Mosfets, High Side and Low Side**
- ✓ **Always ZVS for EMI Filterless**
- ✓ **280Khz for Smaller Transformer/Inductor**
- ✓ **280Khz, Laser Trimming Options for fast turn around**
- ✓ **Optimized efficiency for 25% 50% load**
- ✓ **Proprietary Kick Mode for optimal efficiency, acoustic noise, and output ripple**
- ✓ **All necessary protections with either Latched or Auto-Restart**
- ✓ **800V 30V 5V UHV VIS process**
- ✓ **TSSOP18-Power Package**
- ✓ **Precision: with Precision Laser Trimming**

Slim type/High efficiency/High Power density new topology

(QR-Flyback):



Slim type:
Bridge
Primary side
Mosfet
Secondary side

SMD type

Thermal issue

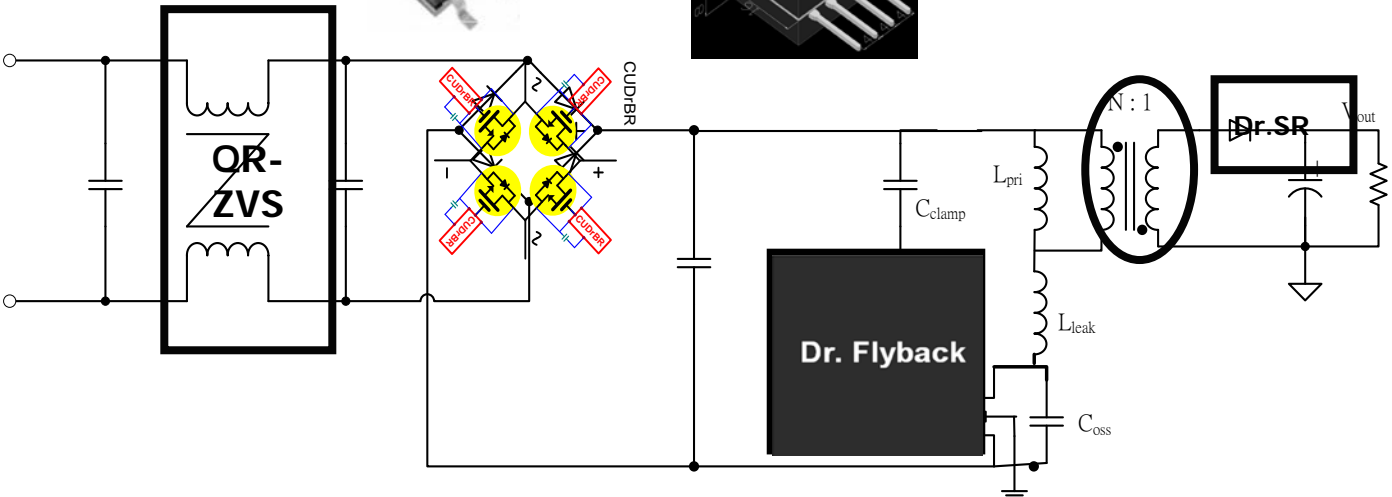
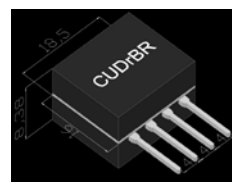
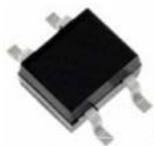
High efficiency

QR is not Z.V.S

High power density

QR FB can not operated high frequency

Efficiency:95 plus Dr.FB/Dr.SR/Dr.Bridge



DR.FB QR resonant topology
Improve Efficiency 3% UP

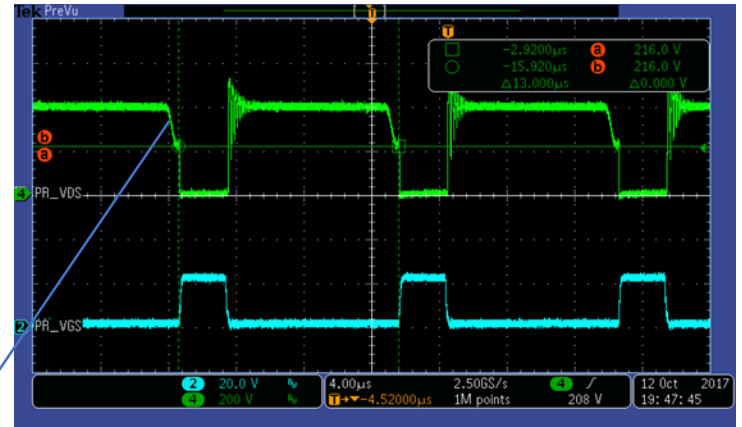
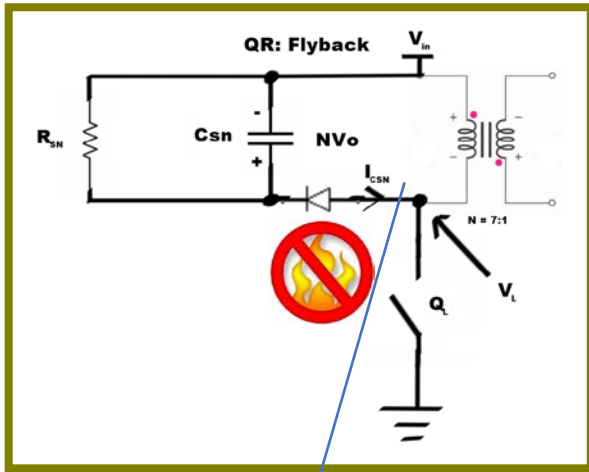
DR.SR:
Improve Efficiency 2% UP

DR. Bridge
Improve Efficiency 1% UP

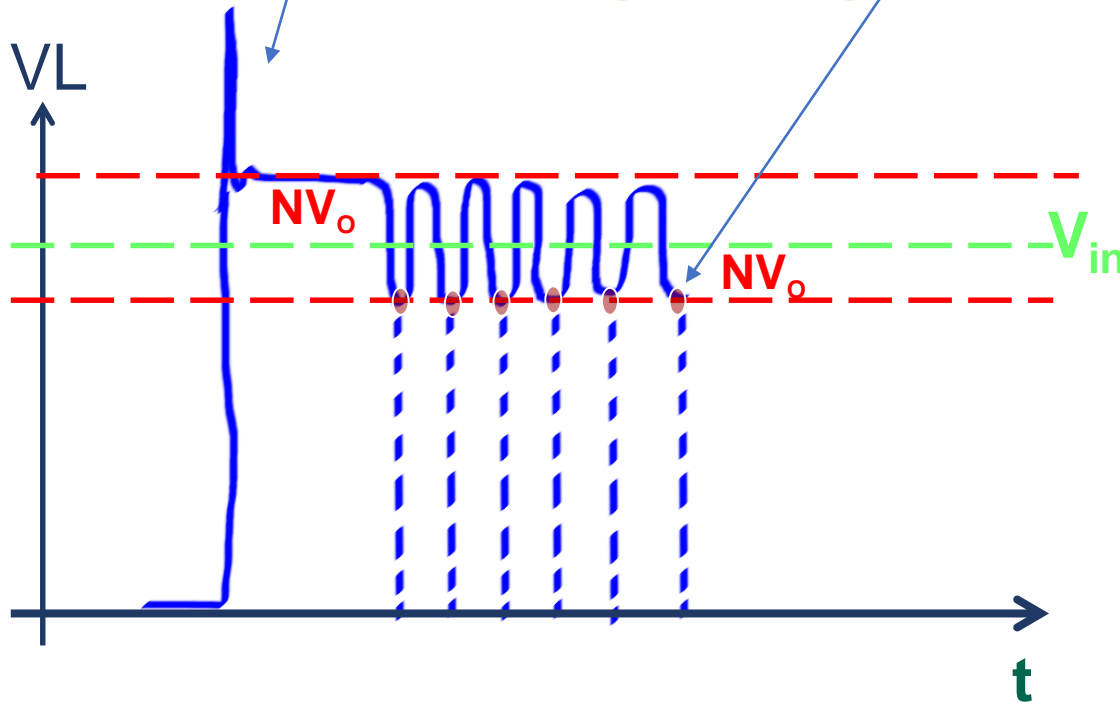
Resonant Flyback ZVS
EMI easy

High frequency
Transformer size reduce

QR Flyback(variable frequency)



Operating High frequency X




$$E = 0.5 \times C \times V(230V_{ac}) \times V(230V_{ac})$$

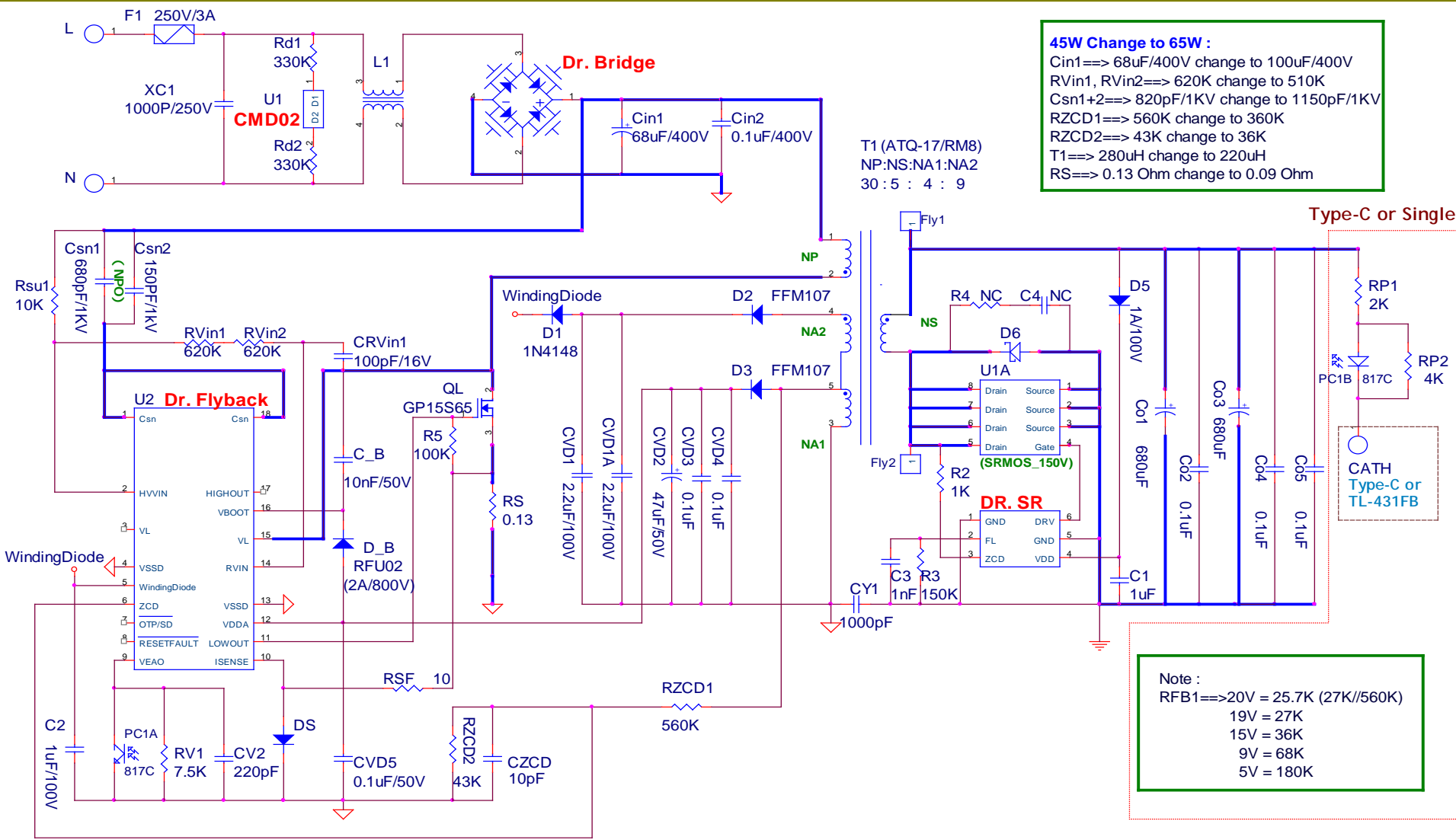
$$= 0.5 \times C(V_L) \times 325V \times 325V$$

$$P_d = E \times f_{sw}$$

$$E \times 280KHz \text{ Vs. } E \times 100KHz$$

Mosfet Thermal Issue
at High Frequency operating 

DR.FB Application Circuit

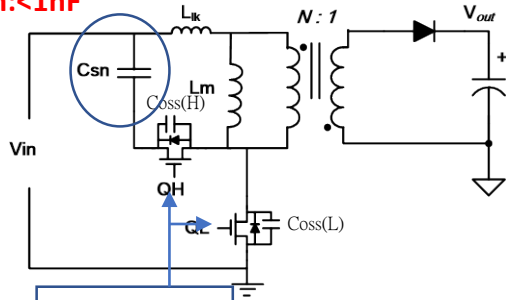


Dr. Flyback™ (TSSOP23)+ Dr. Bridge + Dr. SR 45W/65W Type-C Circuit

Dr. Flyback™ VS A.C.F Compare

Dr. Flyback™

$C_{sn} < 1nF$



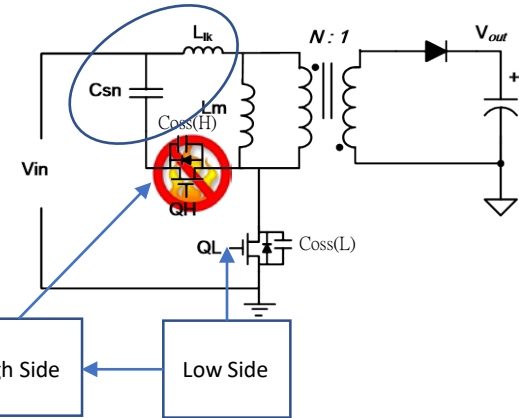
Dr. Flyback™

Adaptive Control High Side and Low Side

- $C_{sn} < 3nF \sim 1nF$
- High side 4A/650V SJ Mosfet

A.C.F

$C_{sn} > 100nF \sim 400nF$
Or +external inductor



Complementary control

- $C_{sn} > 10nF \sim 100nF$ or need external inductor
- High side MosFET Gan 20A

Dr. Flyback

Close Loop:

1. HighSide ON = (SelfDetermination after Permission from LowSide)
2. Not Complimentary Duty Cycle; HighSide only ONs when it is needed
3. It has its own Brain
4. HighSide ZVS(On) ● ZVS(Off) and LowSide ZVS(On)

ACF

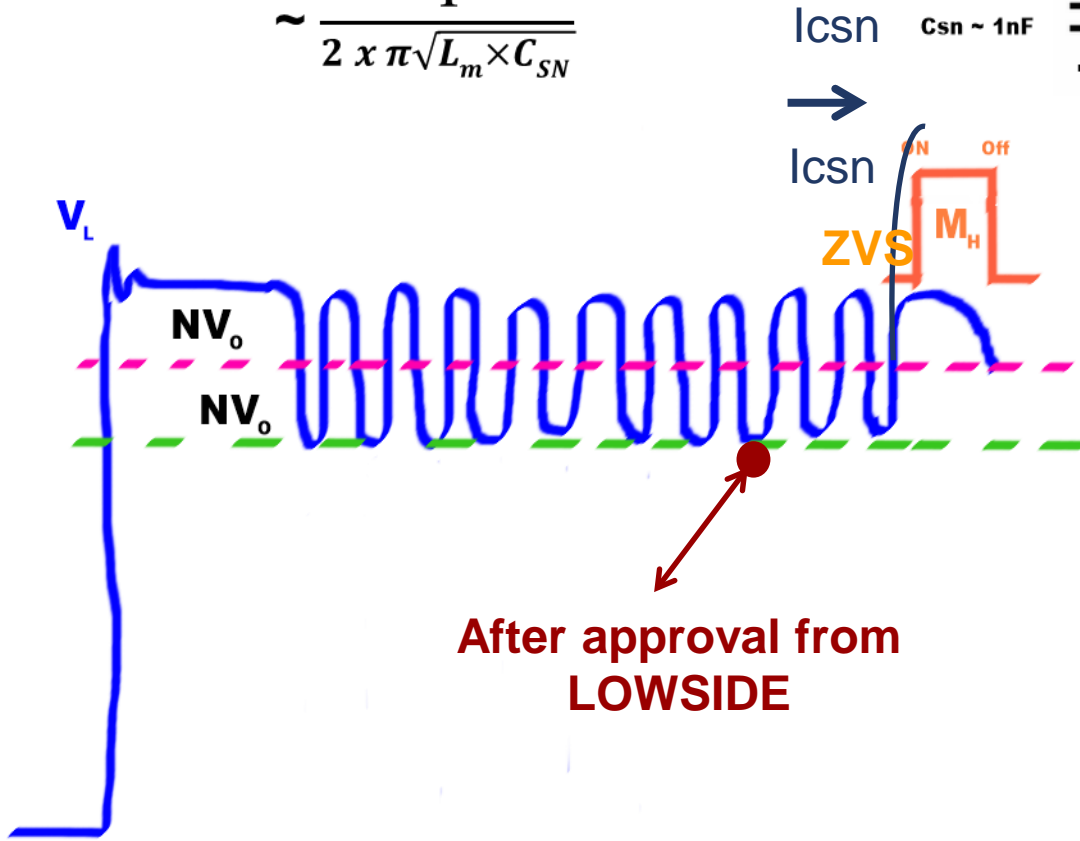
Open Loop:

1. Complementary Duty Cycle
2. Dead Time Control
3. Sensitive to Tpd (So use GaN Driver IC) Need GaN HighSide Driver
4. $C_{sn} \sim 400nF$ (400 X Bigger)
5. Must Use GaN
6. Cannot go to DCM at LightLoad due to Not ZVS and ...
7. Audible Noise
8. Need Rsn ~> More Components and More Loss
9. HighSide SW is not ZVS
10.

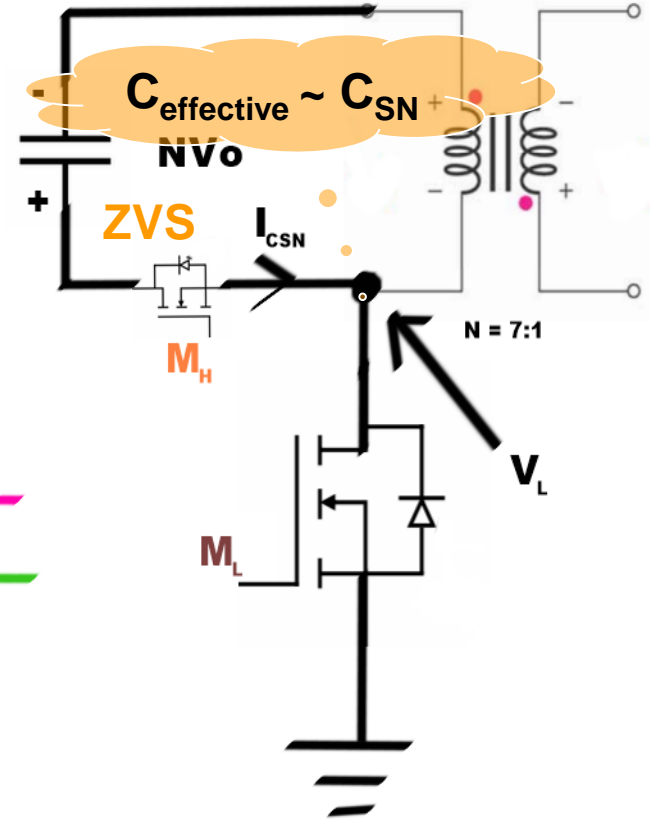
**Dr. Flyback™
HighSide ON**

$$f_r = \frac{1}{2 \times \pi \sqrt{L_m \times C_{effective}}}$$

$$\sim \frac{1}{2 \times \pi \sqrt{L_m \times C_{SN}}}$$



Dr. Flyback™

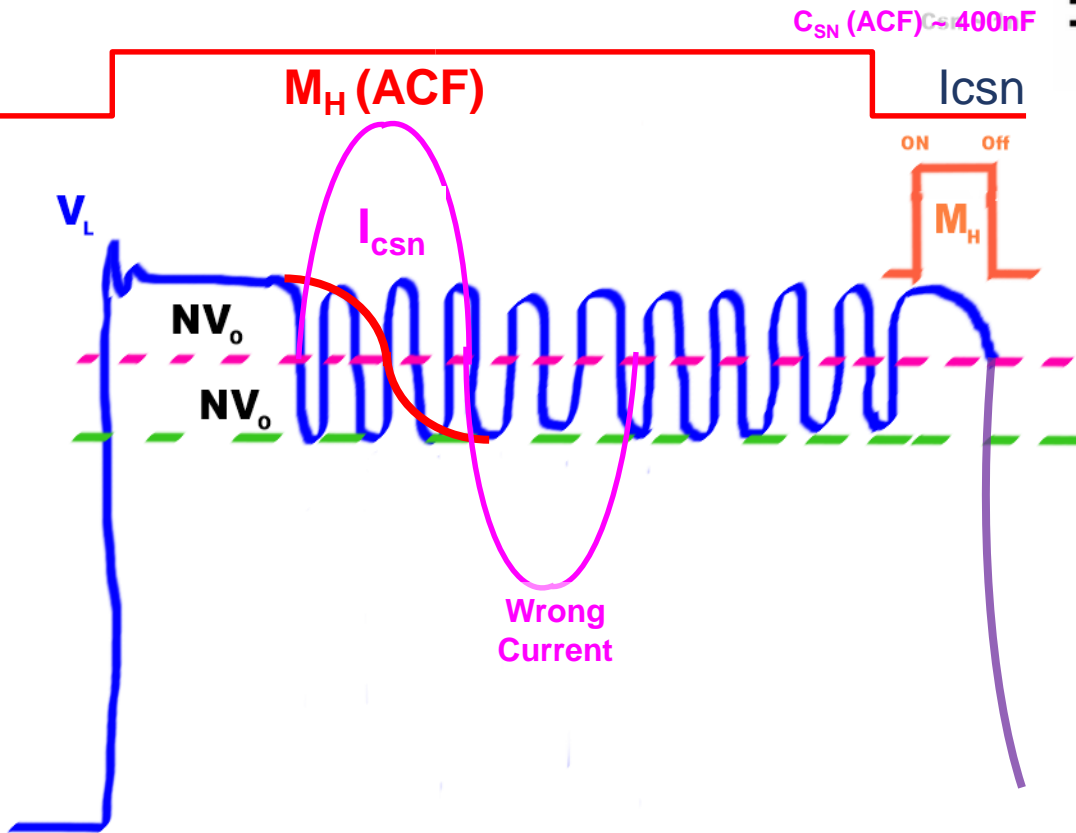


A.C.F: Active Clamp Flyback Issues

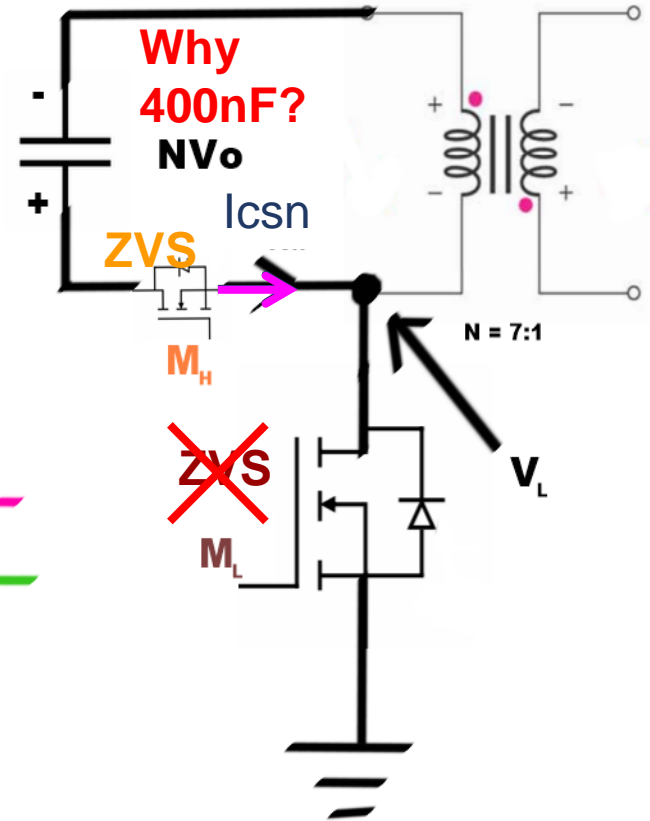
ACF:

OPEN LOOP Control, Dead time control:

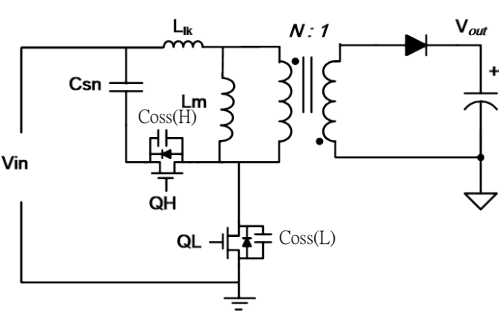
- $C_{SN} (ACF) \sim 400 \times C_{SN} (\text{Dr. Flyback}^{\text{TM}}) \sim 400\text{nF}$
- Must Use GaN Fets and GaN Driver IC



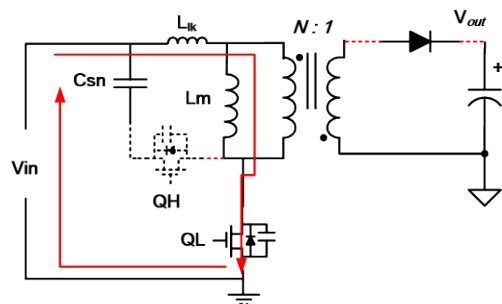
~~Dr. Flyback~~TM



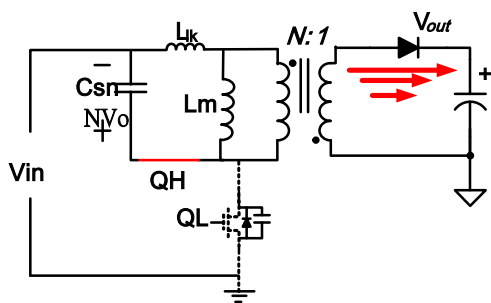
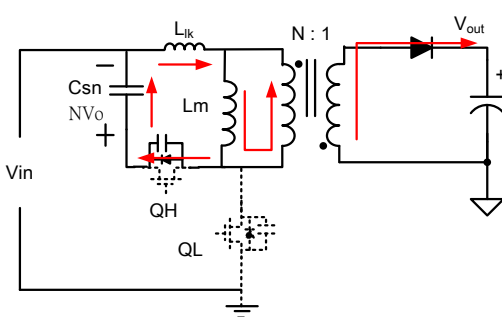
Dr Flyback™



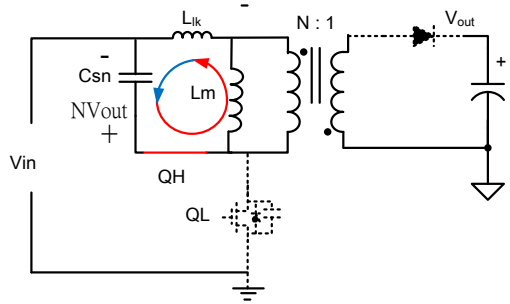
t0-t1



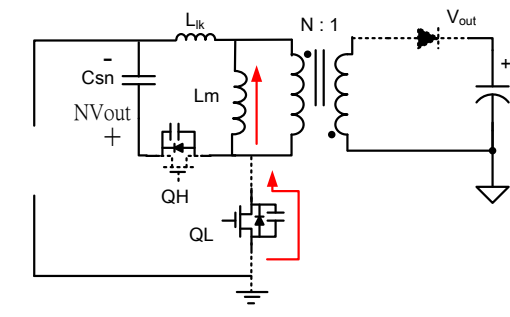
t1-t2



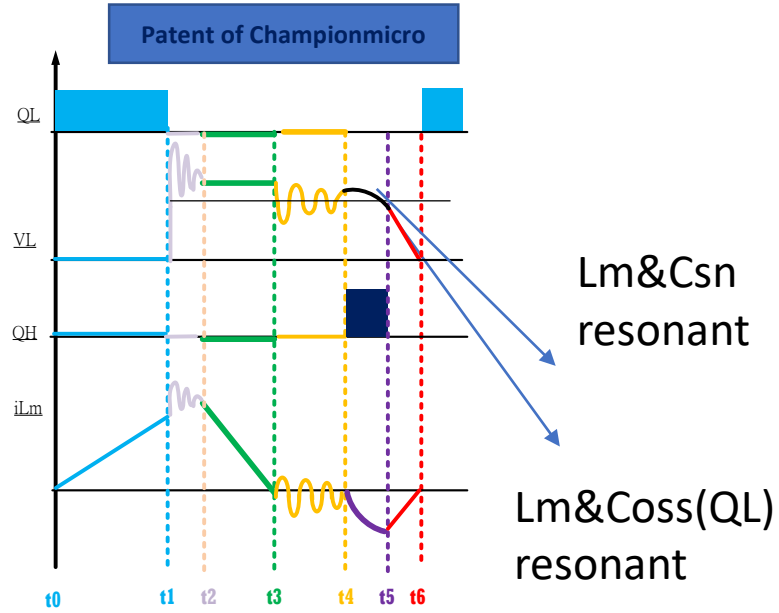
t3-t4



t4-t5

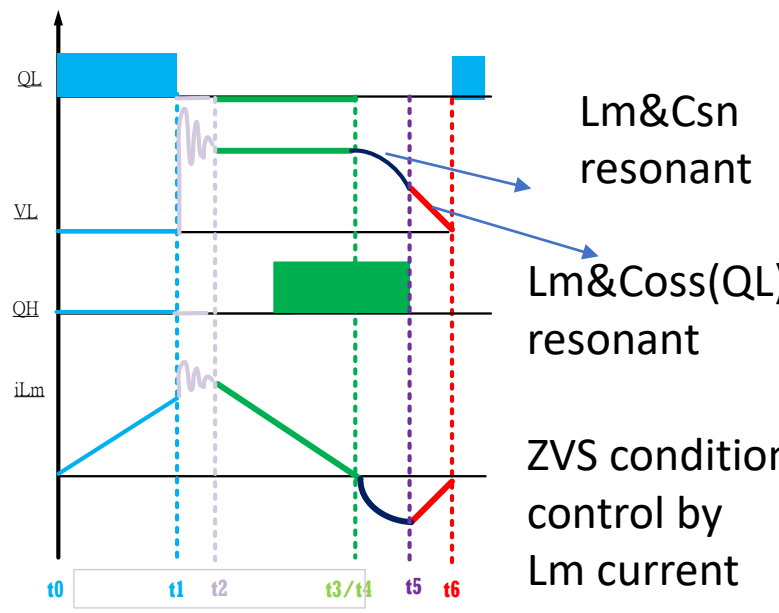


t5-t6



Lm & Csn resonant

Lm & Coss(QL) resonant



Lm & Csn resonant

Lm & Coss(QL) resonant

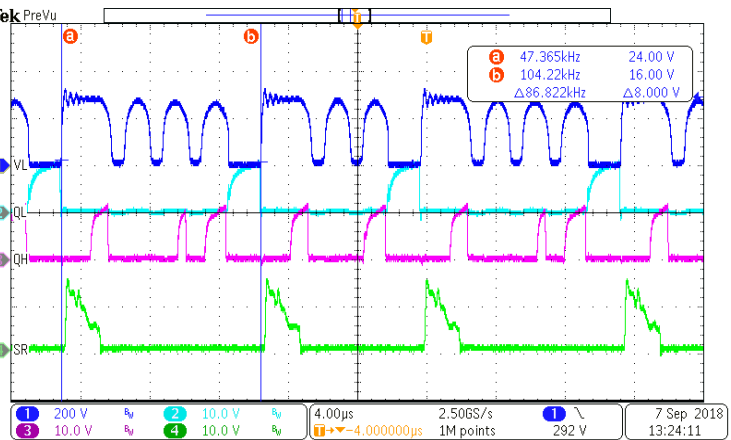
ZVS condition control by Lm current

Qusai Flyback/**Dr. Flyback™**/Active clamp Flyabck compare table

QR FB VS Dr.FB VS ACF			
Control Method	Qusai-Resonant	Dr Flyback	ACF
Operating frequency	Variable frequency	Variable frequency	Variable frequency
Operating Mode	DCM/CRM	DCM/CRM	CRM/CCM
High side driver	X	O	O
High Side Mosfet	X	Small	Big
High Side Mosfet	X	ZVS	Diffcult all condiction control ZVS
Low side Mosfet	Valley switch	ZVS	Diffcult all condiction control ZVS
Z.V.S condition	X	Lm	Llk
Z.V.S condition	X	Csn small easy achive	External inductor or big Csn
EMI	Bad	Good	Middle
SR control	Easy	Easy	Diffcult
High frequency operating	limit	Easy	Easy
Efficiency	Middle	Excellent	Good

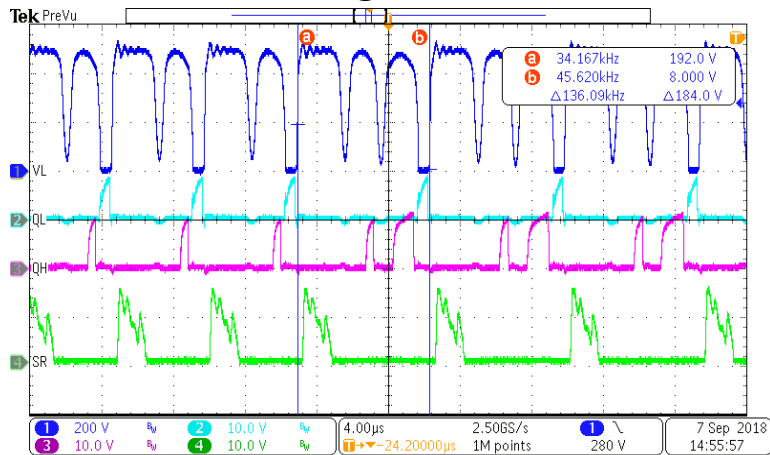
Dr. Flyback™ Operating Waveform

115VAC Light Load

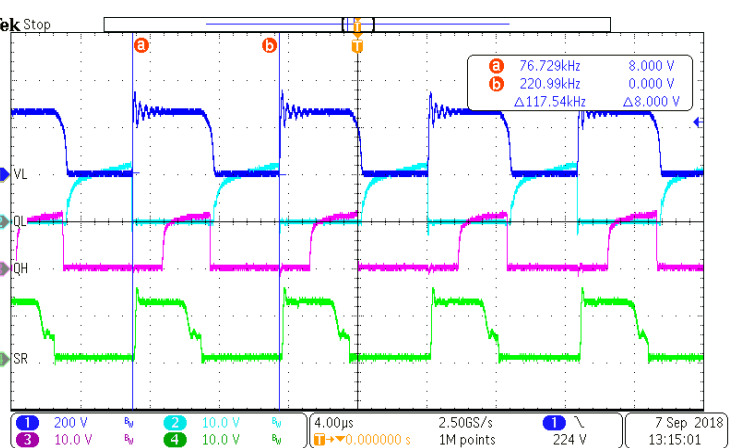


115VAC Mosfet switch at VDS~0V

230VAC light Load

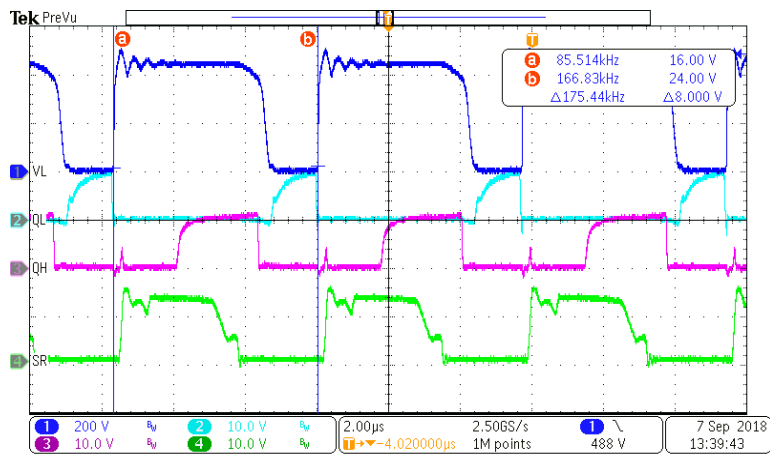


115VAC 100% load



230VAC Mosfet switch at VDS~30V

230VAC 100% load



Dr. Flyback™ 45W & 65W Efficiency

45W_115VAC & 230VAC Efficiency

115VAC @ 20V @60Hz							
1.RM8(30:5:4:9) 2.Lm=280uH 3.Csn=830pF 4.Bulk Cap=68uF 5. Lowside MOS:GP15S65 6.Highside MOS:GP04S65 7.SR MOS:BSC093N15							
Mode	Load	Vout	Iout	Pout	Pin	EFF	Fsw(KHz)
KICK	10%	20.04	0.225	4.51	4.95	91.09%	
DCM	25%	20.04	0.563	11.27	12.46	90.47%	125 ~ 93
CRM	50%	20.04	1.125	22.55	24.36	92.55%	170-181
CRM	75%	20.04	1.688	33.82	36.22	93.37%	130-147
CRM	100%	20.05	2.250	45.11	48.25	93.50%	100-123

230VAC @ 20V @50Hz							
1.RM8(30:5:4:9) 2.Lm=280uH 3.Csn=830pF 4.Bulk Cap=68uF 5. Lowside MOS:GP15S65 6.Highside MOS:GP04S65 7.SR MOS:BSC093N15							
Mode	Load	Vout	Iout	Pout	Pin	EFF	Fsw(KHz)
KICK	10%	20.04	0.225	4.51	4.96	90.91%	
KICK	25%	20.04	0.563	11.27	12.3	91.65%	
DCM	50%	20.04	1.125	22.55	24.44	92.25%	137
CRM	75%	20.04	1.688	33.82	36.26	93.26%	200-205
CRM	100%	20.05	2.250	45.11	48.18	93.63%	171-177

65W_115VAC & 230VAC Efficiency

115VAC @ 20V @60Hz							
1.RM8(30:5:9:4) 2.Lm=220uH 3.Csn=1150pF 4.Bulk Cap=100uF 5. Lowside MOS:GP15S65 6.Highside MOS:GP04S65 7.SR MOS:BSC093N15							
Mode	Load	Vout	Iout	Pout	Pin	EFF	Fsw(KHz)
KICK	10%	20.04	0.325	6.51	7.232	90.06%	
DCM	25%	20.04	0.813	16.28	17.78	91.58%	123
CRM	50%	20.04	1.625	32.57	35.02	92.99%	163-177
CRM	75%	20.04	2.438	48.85	52.34	93.33%	122-135
CRM	100%	20.04	3.250	65.13	69.86	93.23%	93-117

230VAC @ 20V @50Hz							
1.RM8(30:5:9:4) 2.Lm=220uH 3.Csn=1150pF 4.Bulk Cap=100uF 5. Lowside MOS:GP15S65 6.Highside MOS:GP04S65 7.SR MOS:BSC093N15							
Mode	Load	Vout	Iout	Pout	Pin	EFF	Fsw(KHz)
KICK	10%	20.03	0.325	6.51	7.2	90.41%	
KICK	25%	20.04	0.813	16.28	18.03	90.31%	
CRM	50%	20.04	1.625	32.57	34.99	93.07%	230
CRM	75%	20.04	2.438	48.85	52.01	93.92%	186-191
CRM	100%	20.05	3.250	65.16	69.2	94.17%	157-165